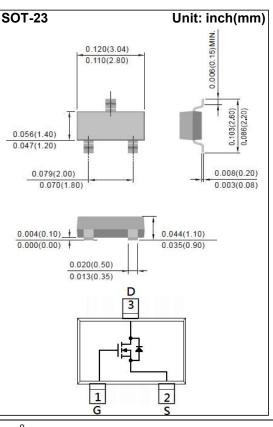


CSM620N3S23 60V N-Channel Enhancement Mode MOSFET Voltage 60 V Current 3A

Features

- RDS(ON), VGS@10V, ID@2.0A<60mΩ
- RDS(ON), VGS@4.5V, ID@1.0A<75m Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc



- Mechanical Data
- Case: SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams

Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

PARAME	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current		ID	3	Α
Pulsed Drain Current (Note 4)		I _{DM}	12	А
Power Dissipation	T _a =25°C		1.25	W
	Derate above 25°C	PD	10	mW/ °C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient ^(Note 3)		R _{eja}	100	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			_			
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.75	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_{D} =2.0A	-	55	60	mΩ
		V _{GS} =4.5V, I _D =1.0A	-	60	75	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =48V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 5)		·	·			
Total Gate Charge	Qg		-	9.3	-	nC
Gate-Source Charge	Q_gs	V _{DS} =48V, I _D =2.0A, V _{GS} =10V ^(Note 1,2)	-	2.2	-	
Gate-Drain Charge	Q_gd		-	1.9	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	509	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	23	-	
Turn-On Delay Time	td _(on)		-	3.2	-	
Turn-On Rise Time	tr	$V_{DD}=30V, I_{D}=2.0A,$ $V_{GS}=10V,$ $R_{G}=3.3\Omega^{(Note 1.2)}$	-	9.7	-	ns
Turn-Off Delay Time	td _(off)		-	18.5	-	
Turn-Off Fall Time	tf	R_{G} -3.3 Ω	-	6.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					2.5	•
Diode Forward Current	I _S		-	-	2.5	A
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.77	1.2	V

NOTES :

1. Pulse width <300us, Duty cycle <2%

2. Essentially independent of operating temperature typical characteristics.

3. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.

4. The maximum current rating is package limited.

5. Guaranteed by design, not subject to production testing.



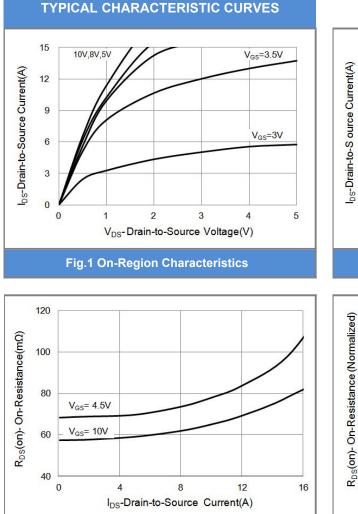
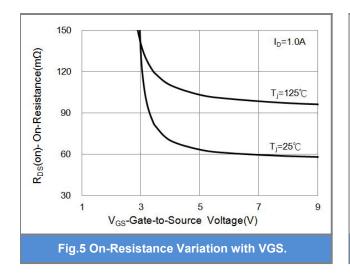


Fig.3 On-Resistance vs. Drain Current



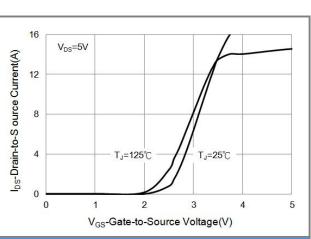


Fig.2 Transfer Characteristics

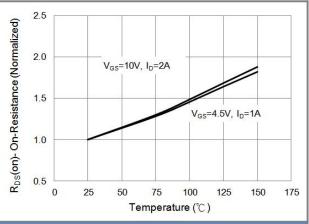
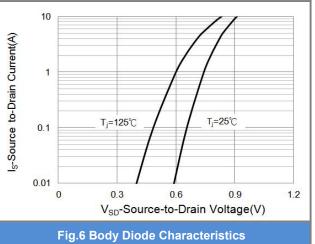
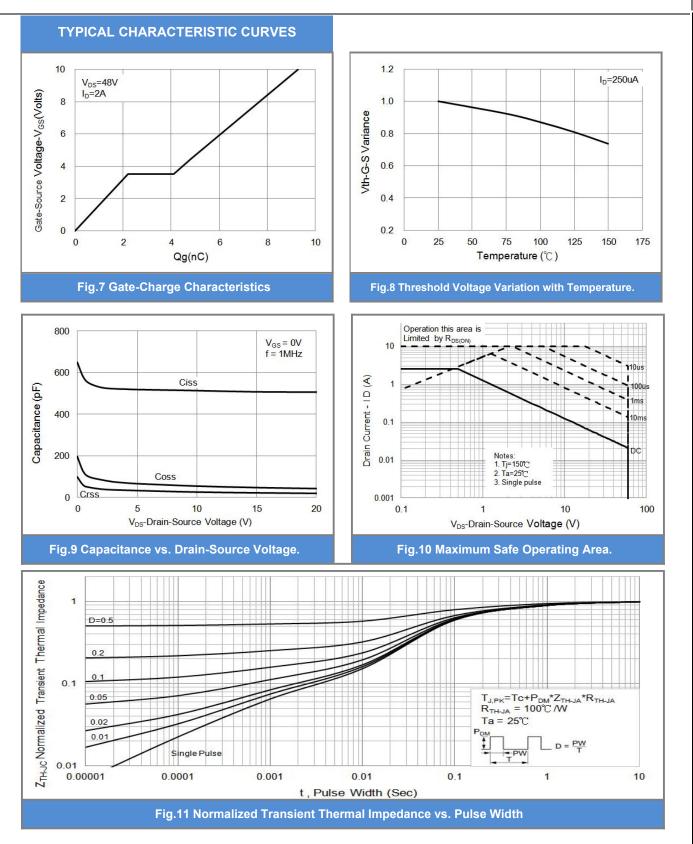


Fig.4 On-Resistance vs. Junction temperature





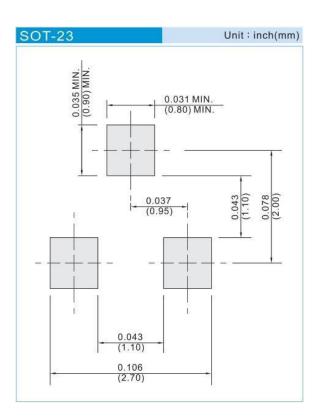




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type		
CSM620N3S23	SOT-23	3K pcs / 7" reel		

MOUNTING PAD LAYOUT





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